1. General description

NPN/NPN Resistor-Equipped double Transistors (RET) in an ultra small DFN1412-6 (SOT1268) leadless Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PRMD13.

2. Features and benefits

- 100 mA output current capability
- · Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- · Reduces pick and place costs
- · Low package height of 0.5 mm
- AEC-Q101 qualified

3. Applications

- Digital applications
- · Cost-saving alternative to BC847/BC857 series in digital applications
- Control of IC inputs
- · Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor	Per transistor							
V _{CEO}	collector-emitter voltage	open base		-	-	50	V	
Io	output current			-	-	100	mA	
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		100	-	-		
R1	bias resistor 1	T _{amb} = 25 °C	[1]	3.3	4.7	6.1	kΩ	
R2/R1	bias resistor ratio		[1]	8	10	12		

^[1] See section "Test information" for resistor calculation and test conditions.



50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		6 5 4
2	I1	input (base) TR1	7 6	
3	O2	output (collector) TR2	2 5	R1 R2
4	GND2	GND (emitter) TR2		TR1
5	12	input (base) TR2	[3] [4]	R2 R1
6	01	output (collector) TR1	Transparent top view	
7	01	output (collector) TR1	DFN1412-6 (SOT1268)	1 2 3
8	O2	output (collector) TR2	,	sym063

6. Ordering information

Table 3. Ordering information

Type number	Package	age				
	Name	Description	Version			
PRMH13	DFN1412-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body: 1.4 mm x 1.2 mm x 0.47 mm	SOT1268			

7. Marking

Table 4. Marking codes

Type number	Marking code
PRMH13	C4

50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

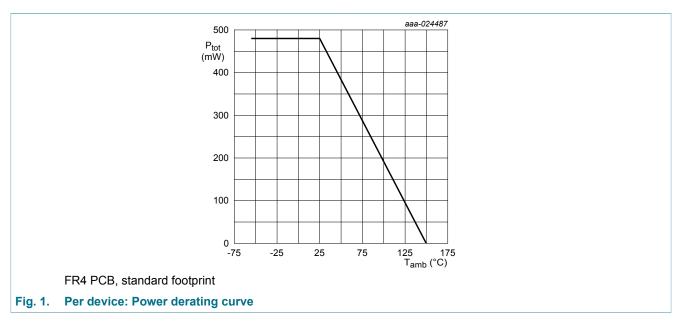
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transisto	or		,			
V _{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
V _I	input voltage	positive		-	30	V
		negative		-	-5	V
lo	output current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	325	mW
Per device	'			'	'	'
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	480	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transis	tor			,			
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	385	K/W
Per device				,			
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	261	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

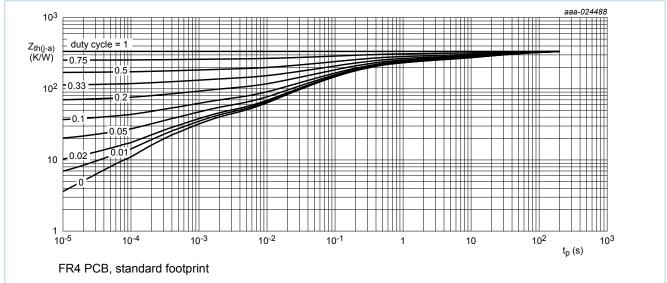


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

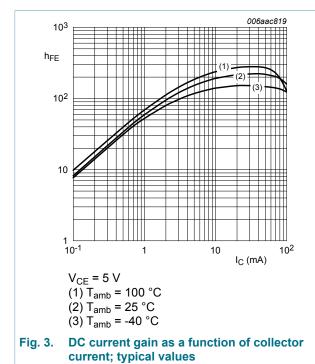
50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
I _{CBO}	collector-base cut-off current (emitter open)	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	100	nA
CLO	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	1	μΑ
	current (base open)	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current (collector open)	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	170	μΑ
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 10 mA; T _{amb} = 25 °C		100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 5 \text{ mA}$; $I_B = 0.25 \text{ mA}$; $T_{amb} = 25 \text{ °C}$		-	-	100	mV
$V_{I(off)}$	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		-	0.6	0.5	V
V _{I(on)}	on-state input voltage	V _{CE} = 0.3 V; I _C = 5 mA; T _{amb} = 25 °C		1.3	0.9	-	V
R1	bias resistor 1	T _{amb} = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	
C _C	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	2.5	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	230	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor



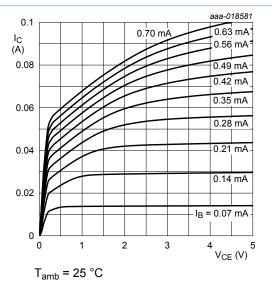


Fig. 4. Collector current as a function of collectoremitter voltage; typical values

50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

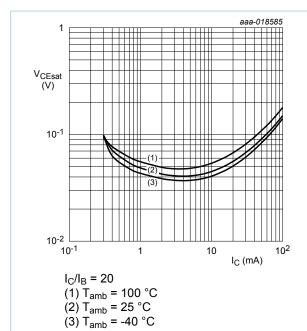
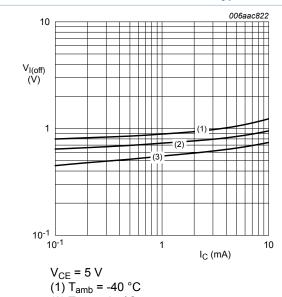


Fig. 5. Collector-emitter saturation voltage as a function of collector current; typical values



(2) T_{amb} = 25 °C (3) T_{amb} = 100 °C Fig. 7. Off-state input voltage as a function of collector current; typical values

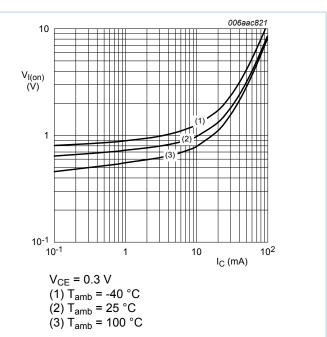


Fig. 6. On-state input voltage as a function of collector current; typical values

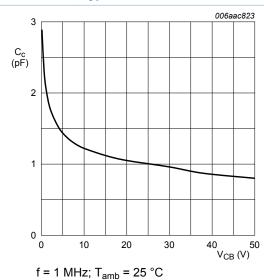
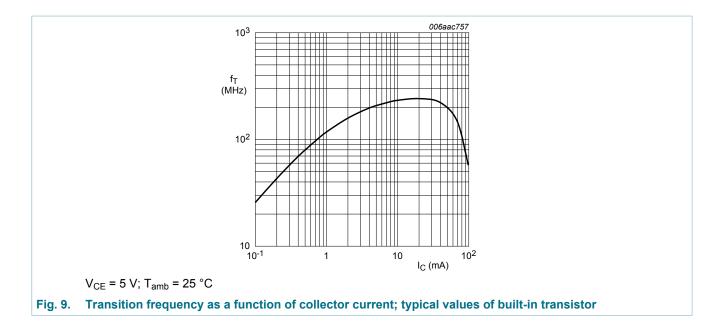


Fig. 8. Collector capacitance as a function of collector-base voltage; typical values

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50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Resistor calculation

· Calculation of bias resistor 1 (R1)

$$RI = \frac{V(I12) - V(I11)}{I12 - I11}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

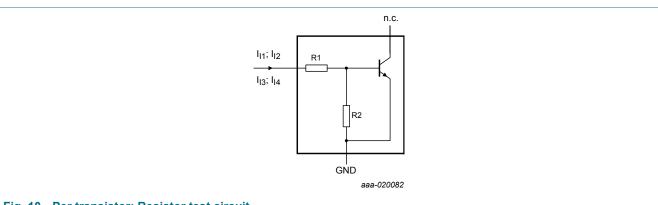


Fig. 10. Per transistor: Resistor test circuit

Resistor test conditions

Table 8. Resistor test conditions

R1 (kΩ)	R2 (kΩ)	Test conditions	est conditions				
		I _{I1}	I _{I2}	I _{I3}	I ₁₄		
4.7	47	90 μΑ	140 μΑ	-55 μΑ	-105 μΑ		

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12. Package outline

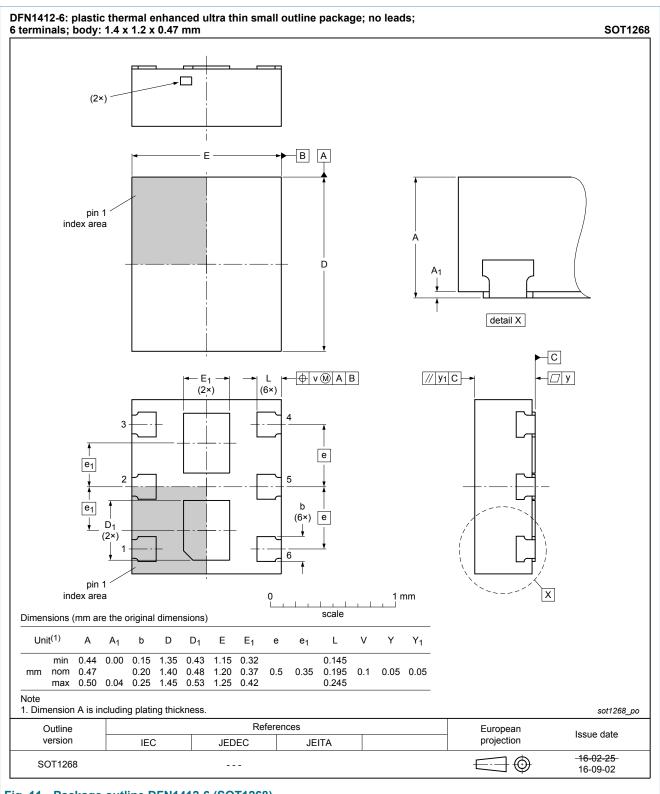
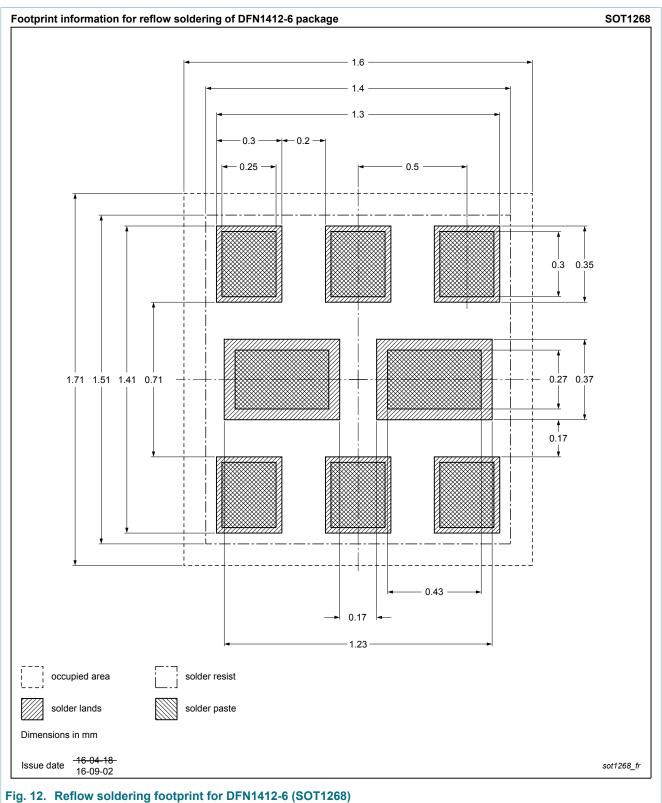


Fig. 11. Package outline DFN1412-6 (SOT1268)

50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

13. Soldering



50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PRMH13 v.1	20170808	Product data sheet	-	-

50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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